EARTH LEAKAGE CURRENT DETECTOR

DESCRIPTION

The UTC **M54123L** is a semiconductor integrated circuit with amplifier for a high-speed earth leakage circuit breaker.

For the amplifying parts of earth leakage circuit breaker, the UTC **M54123L** consists of differential amplifier, latch circuit and voltage regulator.

In normal operating, the UTC **M54123L** should be connected to the secondary side of the ZCT (zero current transformers). Here the ZCT detects leakage current different amplifiers' both input.

Then the signals which have been amplified are integrated by an external capacitor. The integrated signal connects to the input terminal of latch circuit whose output is suitable for the characteristics of high- speed earth leakage circuit breaker.

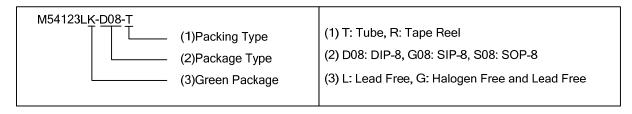
Until the input voltage reaches the fixed level, latch circuit doesn't become high. Then drives a thyristor which is connected to latch circuit's output terminal.

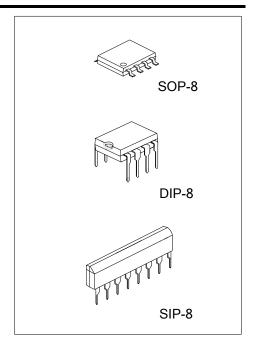
■ FEATURES

- * With good input sensitivity current temperature characteristics
- * High input sensitivity :V_T=6.1mV (Typ.)
- * Only need low external component count
- * High noise and surge-proof
- * Low power dissipation :P_D=5mW (Typ.)
- * May be used both as 100V and 200V.
- * Wide temperature range : from -20 °C to +80°C

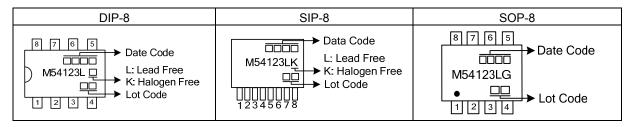
■ ORDERING INFORMATION

Order Number		Packago	Packing	
Lead Free	Halogen Free	Package	Packing	
M54123LK-D08-T	M54123LG-D08-T	DIP-8	Tube	
M54123LK-G08-T	M54123LG-G08-T	SIP-8	Tube	
-	M54123LG-S08-R	SOP-8	Tape Reel	

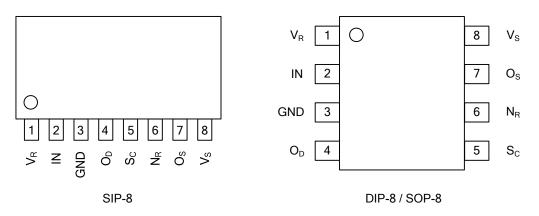




■ MARKING



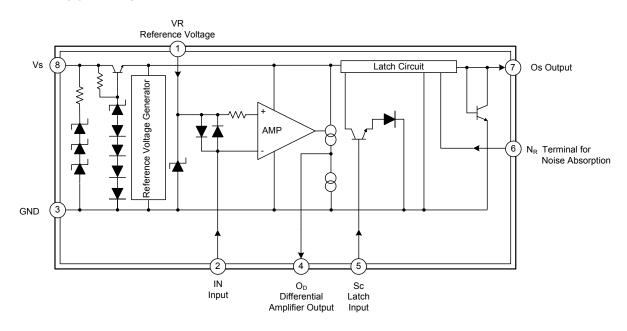
■ PIN CONFIGURATIONS



■ PIN DESCRIPTION

PIN NO.	PIN NAME	DESCRIPTION
1	V_R	Reference voltage terminal
2	IN	Input terminal
3	GND	Ground
4	O _D	Differential amplifier output terminal
5	Sc	Latch input terminal
6	N_R	Terminal for noise absorption
7	Os	Output terminal
8	Vs	Supply voltage terminal

■ BLOCK DIAGRAM



■ ABSOLUTE MAXIMUM RATING (unless otherwise specified)

PARAMETER		SYMBOL	RATINGS	UNIT
Supply Current		Is	8	mA
	Between V _R -IN (Note 2)		250	mA
V _R Pin Current	Between V _R -GND	I_{VR}	30	mA
	Between IN-V _R (Note 2)		-250	mA
IN Terminal Current	Between IN-V _R (Note 2)		250	mA
	Between IN-GND	I _{IN}	30	mA
	Between V _R -IN (Note 2)		-250	mA
S _C Terminal Current		I _{sc}	5	mA
Power Dissipation		P_D	200	mW
Operating Temperature		T_OPR	-20~ +80	°C
Storage Temperature		T_{STG}	-55~ +125	°C

Notes: 1. Absolute maximum ratings are those values beyond which the device could be permanently damaged.

Absolute maximum ratings are stress ratings only and functional device operation is not implied.

■ RECOMMENDED OPERATING CONDITIONS (unless otherwise specified)

PARAMETER	SYMBOL	MIN	TYP	MAX	UNIT
Supply Voltage When Latch Circuit Is Off-State	Vs	12			V
External Capacitor Between Vs and GND	C _{VS}	1			μF
External Capacitor Between Os and GND	Cos			1	μF

■ **ELECTRICAL CHARACTERISTICS** (T_A=-20~+80°C, unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS			TYP	MAX	UNIT
Supply Current	I _{S1}	V _S =12V,V _R -V _I =30mV	T _A =-20°C			580	μA
		(See Test Circuit 1)	T _A =25°C		400	530	μΑ
		(See Test Circuit 1)	T _A =80°C			480	μΑ
Trip Voltage	V _T	V _S =16V, V _R -V _I , T _A =-20~+80°C (Note2) (See Test Circuit 2)		4	6.1	9	mVrms
Timed Current1	I _{TD1}	V _S =16V, V _R -V _I =30mV, V _{OD} =1.2V, T _A =25°C (See Test Circuit 3)		-12		-30	μΑ
Timed Current2	I _{TD2}	V_S =16V, short circuit between V_R and V_I , V_{OD} =0.8V, T_A =25°C (See Test Circuit 4)		17		37	μA
	Io	Vec=1.4V Vec=0.8V	I _{S1} =580μA,T _A =-20°C	-200			μA
Output Current			I _{S1} =530μA,T _A =25°C	-100			μA
			I _{S1} =480μA,T _A =80°C	-75			μΑ
S _C "ON" Voltage (Note3)	V _{SC(ON)}	V _S =16V, T _A =25°C (Se	ee Test Circuit 6)	0.7		1.4	V
S _C Input Current	I _{SC(ON)}	V _S =12V, T _A =25°C (See Test Circuit 7)				5	μΑ
Output Low-Level Current	I _{OSL}	V _S =12V,V _{OSL} =0.2V, T _A =-20~+80°C (See Test Circuit 8)		200			μΑ
Input Clamp Voltage	V _{IC}	V _S =12V, I _{IC} =20mA, T _A =-20~+80°C (See Test Circuit 9)		4.3		6.7	V
Differential Input Clamp Voltage	V _{IDC}	I _{IDC} =100mA, T _A =-20~+80°C (See Test Circuit 10)		0.4		2	V
Maximum Current Voltage	V_{SM}	I _{SM} =7mA, T _A =25°C (See Test Circuit 11)				28	V
Supply Current 2(Note 4)	I _{S2}	V _R -V _I , V _{OS} =0.6V, T _A =-20~+80°C (Note 5) (See Test Circuit 12)				1100	μA
Latch Circuit is Off-State Supply Voltage (Note6)	V _{S(OFF)}	T _A =25°C (See Test Circuit 13)		0.5			V
Operating Time (Note 7)	T _{ON}	V _S =16V,V _R -V _I =0.3V, T _A =25°C (See Test Circuit 14)				4	ms

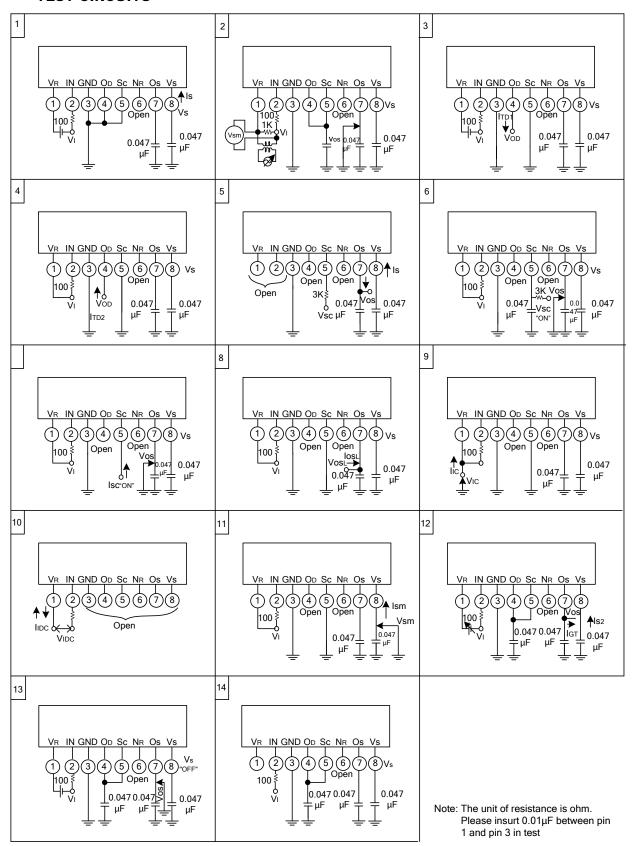
^{2.} Current value between V_R and IN, and between IN and V_R is less than 1ms in the pulse width, and duty cycle is less than 12%, In applying AC current continuously, it is 100 mA in the off-state.

■ ELECTRICAL CHARACTERISTICS (Cont.)

Notes: 1. Typical values are at T_A=25°C

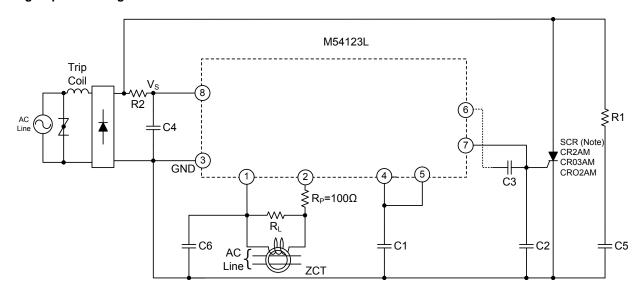
- 2. When standard value of voltage (60Hz) between V_R and V_I is minimum, and output O_S is low-level, or when standard value of voltage (60Hz) between V_R and V_I is maximum, and output O_S is high-level, it is considered as a good one.
- 3. When standard value of voltage V_{SC(ON)} is minimum, and output O_S is low-level, or when standard value of voltage V_{SC(ON)} is maximum, and output O_S is high-level, it is considered as a good one.
- 4. Supply current 2 is necessary to keep high in output O_S.
- 5. After applying 30mV between V_R and V_I and shorting between them, it is considered as a good one if standard value of IGT flows out of output O_{S_L}
- 6. After supply voltage applies 12V and output O_S is high-level, it is considered as a good one in the standard value of supply voltage and in the low-level of output O_S.
- 7. Operating time is a time from applying fixed input till operating latch circuit in $0.047\mu F$ between O_D and GND.

■ TEST CIRCUITS



■ TYPICAL APPLICATION CIRCUIT

High-Speed Leakage Circuit Breaker With UTC M54123L



Note: Gate current must be selected.

Please select voltage resistance by AC supply voltage

Note: The value of R1, R2, C4, and C5 should be chosen in order to keep at least 12V in Vs.

Please connect C4 (>1 μ F) and C2 (<1 μ F).

ZCT and load resistance R_L of ZCT are connected between input pin 1 and 2.

Protective resistance (R_P =100 Ω) must be insurted.

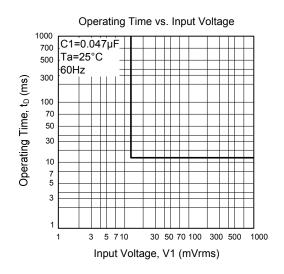
R_L and amplifier's output (in Pin 4) regulates sensitivity current

External capacitor C1 between pin 4 and GND is used for noise removal.

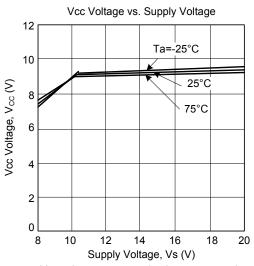
Please connect a varistor or a diode (2 pcs.) to ZCT in parallel, because of when large current is grounded in the primary side (AC line) of ZCT, the following situation can be abandoned: The wave form in the secondary side of ZCT is distorted and some signals do not appear in the output of amplifier.

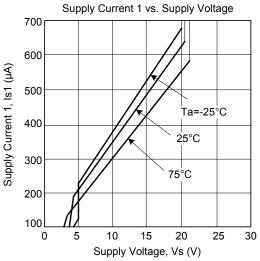
Please connect capacitor (about 0.047µF) between pin 6 and pin 7.

Capacitor C6 between pin 1 and GND is about 0.047µF for removing noise.

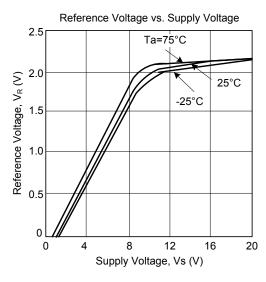


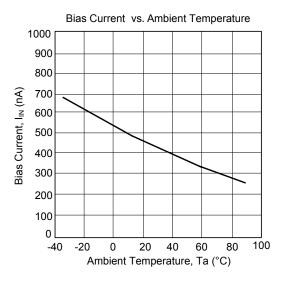
■ TYPICAL CHARACTERISTICS

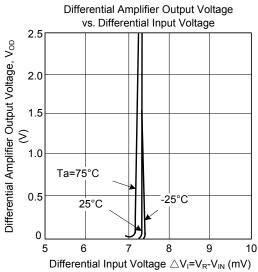


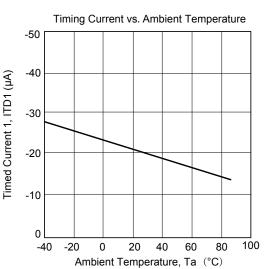


Vcc voltage generates by the constant voltage circuit in IC. This is measured not by M54123L but by a special element.









■ TYPICAL CHARACTERISTICS(Cont.)

